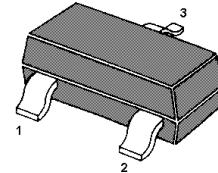
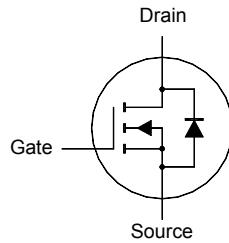


MMFTN170

N-Channel Enhancement Mode Field Effect Transistor

Feature

- Voltage controlled small signal switch
- High saturation current capability



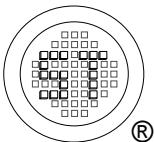
1. Gate 2. Source 3. Drain
TO-236 Plastic Package

Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	60	V
Drain-Gate Voltage ($R_{GS} \leq 1 \text{ M}\Omega$)	V_{DGR}	60	V
Gate-Source Voltage	V_{GSS}	± 20	V
Drain Current - Continuous	I_D	500	mA
Drain Current - Pulsed		800	
Total Power Dissipation	P_{tot}	300	mW
Operating and Storage Temperature Range	T_j, T_{stg}	- 55 to + 150	°C

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage at $I_D = 100 \mu\text{A}$	$V_{(BR)DSS}$	60	-	-	V
Zero Gate Voltage Drain Current at $V_{DS} = 25 \text{ V}$	I_{DSS}	-	-	0.5	μA
Gate-Body Leakage, Forward at $V_{GS} = 15 \text{ V}$	I_{GSSF}	-	-	10	nA
Gate-Source Threshold Voltage at $V_{DS} = V_{GS}, I_D = 1 \text{ mA}$	$V_{GS(\text{th})}$	0.8	-	3	V
Static Drain-Source On-Resistance at $V_{GS} = 10 \text{ V}, I_D = 200 \text{ mA}$	$R_{DS(\text{on})}$	-	-	5	Ω
Forward Transconductance at $V_{DS} \geq 2 V_{DS(\text{on})}, I_D = 200 \text{ mA}$	g_{FS}	-	320	-	mS
Input Capacitance at $V_{DS} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{iss}	-	-	40	pF
Output Capacitance at $V_{DS} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{oss}	-	-	30	pF
Reverse Transfer Capacitance at $V_{DS} = 10 \text{ V}, f = 1 \text{ MHz}$	C_{rss}	-	-	10	pF
Turn-On Time at $V_{DD} = 25 \text{ V}, I_D = 500 \text{ mA}, V_{GS} = 10 \text{ V}, R_{GEN} = 50 \Omega$	$t_{(\text{on})}$	-	-	10	ns
Turn-Off Delay Time at $V_{DD} = 25 \text{ V}, I_D = 500 \text{ mA}, V_{GS} = 10 \text{ V}, R_{GEN} = 50 \Omega$	$t_{(\text{off})}$	-	-	10	ns



SEMTECH ELECTRONICS LTD.



ISO TS 16949 : 2009 ISO 14001 : 2004 ISO 9001 : 2008 BS-OHSAS 18001 : 2007 IECQ QC 080000 Certificate No. 160719000 Certificate No. 7116 Certificate No. 50713410 Certificate No. 7116 Certificate No. PRC-HSPM-1404-1

Dated: 16/03/2015 Rev:01